# RGE60TS65DGC13

## 650V 30A Field Stop Trench IGBT

Datasheet

V <sub>CES</sub>	650V
I <sub>C</sub>	30A
V <sub>CE(sat) (Typ.)</sub>	1.65V
$P_{D}$	166W

# Outline TO-247GE

#### Features

- 1) Low Collector Emitter Saturation Voltage
- 2) Low Switching Loss
- 3) Short Circuit Withstand Time 5µs
- 4) Built in Very Fast & Soft Recovery FRD
- 5) Pb free Lead Plating; RoHS Compliant

## Application

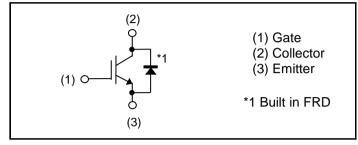
General Inverter

**UPS** 

**Power Conditioner** 

Welder

#### ●Inner Circuit



Packaging Specifications

Tackaging Specifications					
	Packaging	Tube			
	Reel Size (mm)	-			
Type	Tape Width (mm)	-			
Type	Basic Ordering Unit (pcs)	600			
	Packing Code	C13			
	Marking	RGE60TS65D			

# ● Absolute Maximum Ratings (at T<sub>C</sub> = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V <sub>CES</sub>	650	V
Gate - Emitter Voltage		V <sub>GES</sub>	±30	V
Calleston Comment	$T_C = 25^{\circ}C$	I <sub>C</sub>	51	А
Collector Current	T <sub>C</sub> = 100°C	I <sub>C</sub>	32	Α
Pulsed Collector Current		I <sub>CP</sub> <sup>*1</sup>	90	Α
Diode Forward Current	T <sub>C</sub> = 25°C	I <sub>F</sub>	43	Α
	T <sub>C</sub> = 100°C	I <sub>F</sub>	26	Α
Diode Pulsed Forward Current		I <sub>FP</sub> *1	90	Α
Power Dissipation	T <sub>C</sub> = 25°C	P <sub>D</sub>	166	W
	T <sub>C</sub> = 100°C	P <sub>D</sub>	83	W
Operating Junction Temperature		T <sub>j</sub>	-40 to +175	°C
Storage Temperature		T <sub>stg</sub>	-55 to +175	°C

<sup>\*1</sup> Pulse width limited by T<sub>jmax.</sub>

## ●Thermal Resistance

Parameter	Cumbal	Values			Unit
Farameter	Symbol	Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	ı	0.90	°C/W
Thermal Resistance Diode Junction - Case	$R_{\theta(j-c)}$	-	ı	1.48	°C/W

# ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
- raiametei	Symbol	Conditions	Min.	Тур.	Max.	Offic
Collector - Emitter Breakdown Voltage	BV <sub>CES</sub>	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	ı	ı	V
Collector Cut - off Current	I <sub>CES</sub>	$V_{CE} = 650V, V_{GE} = 0V$	-	ı	10	μΑ
Gate - Emitter Leakage Current	I <sub>GES</sub>	$V_{GE} = \pm 30V, V_{CE} = 0V$	-	1	±200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = 5V, I_{C} = 8.2mA$	5.0	6.0	7.0	V
Collector - Emitter Saturation		$I_C = 30A, V_{GE} = 15V,$		4.05	0.05	.,
Voltage	V <sub>CE(sat)</sub>	$T_j = 25^{\circ}C$ $T_j = 175^{\circ}C$	-	1.65 2.15	2.05 -	V

# •IGBT Electrical Characteristics (at $T_j = 25$ °C unless otherwise specified)

Parameter	0	Conditions	Values			I I a it
	Symbol		Min.	Тур.	Max.	Unit
Input Capacitance	C <sub>ies</sub>	$V_{CE} = 30V$ ,	-	1854	-	
Output Capacitance	C <sub>oes</sub>	$V_{GE} = 0V$ ,	-	84	-	pF
Reverse transfer Capacitance	C <sub>res</sub>	f = 1MHz	-	20	-	
Total Gate Charge	$Q_g$	V <sub>CE</sub> = 400V,	-	63	-	
Gate - Emitter Charge	$Q_ge$	$I_{\rm C} = 30A$ ,	-	15	-	nC
Gate - Collector Charge	$Q_{gc}$	$V_{GE} = 15V$	-	28	-	
Turn - on Delay Time	t <sub>d(on)</sub>		-	40	-	
Rise Time	t <sub>r</sub>	$I_C = 30A, V_{CC} = 400V,$ $V_{GF} = 15V, R_G = 10\Omega,$	-	16	-	ns
Turn - off Delay Time	$t_{d(off)}$	$T_i = 25^{\circ}C$	1	114	-	
Fall Time	t <sub>f</sub>	Inductive Load *E <sub>on</sub> include diode reverse recovery	•	78	-	
Turn-on Switching Loss	E <sub>on</sub>		•	0.64	-	mJ
Turn-off Switching Loss	E <sub>off</sub>		•	0.57	-	
Turn - on Delay Time	t <sub>d(on)</sub>	$I_C = 30A$ , $V_{CC} = 400V$ , $V_{GE} = 15V$ , $R_G = 10\Omega$ , $T_i = 175$ °C	-	39	-	ns
Rise Time	t <sub>r</sub>		•	18	-	
Turn - off Delay Time	$t_{d(off)}$		-	127	-	
Fall Time	t <sub>f</sub>	Inductive Load	-	107	-	
Turn-on Switching Loss	$E_{on}$	*E <sub>on</sub> include diode reverse recovery	-	0.69	-	mJ
Turn-off Switching Loss	$E_{off}$		-	0.75	-	1110
Reverse Bias Safe Operating Area	RBSOA	$I_C = 90A$ , $V_{CC} = 520V$ , $V_p = 650V$ , $V_{GE} = 15V$ , $R_G = 100\Omega$ , $T_j = 175^{\circ}C$	FULL SQUARE		-	
Short Circuit Withstand Time	t <sub>sc</sub>	$V_{CC} \le 360V$ , $V_{GE} = 15V$ , $T_j = 25^{\circ}C$	5	-	-	μs

# ●FRD Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Parameter	Coursels al	Conditions	Values			1.1
	Symbol		Min.	Тур.	Max.	Unit
Diode Forward Voltage	V <sub>F</sub>	$I_F = 30A,$ $T_j = 25^{\circ}C$	-	1.6	2.05	V
		T <sub>j</sub> = 175°C	-	1.65	-	
Diode Reverse Recovery Time	t <sub>rr</sub>		-	166	-	ns
Diode Peak Reverse Recovery Current	I <sub>rr</sub>	$I_F = 30A,$ $V_{CC} = 400V,$ $di_F/dt = 500A/\mu s,$ $T_j = 25^{\circ}C$	-	11.0	1	А
Diode Reverse Recovery Charge	Q <sub>rr</sub>		-	0.9	ı	μC
Diode Reverse Recovery Energy	E <sub>rr</sub>		-	168	ı	μJ
Diode Reverse Recovery Time	t <sub>rr</sub>	$I_F = 30A,$ $V_{CC} = 400V,$ $di_F/dt = 500A/\mu s,$ $T_j = 175^{\circ}C$	-	190	-	ns
Diode Peak Reverse Recovery Current	I <sub>rr</sub>		-	13.3	1	А
Diode Reverse Recovery Charge	Q <sub>rr</sub>		-	1.5	-	μC
Diode Reverse Recovery Energy	E <sub>rr</sub>		-	320	-	μJ

#### • Electrical Characteristic Curves

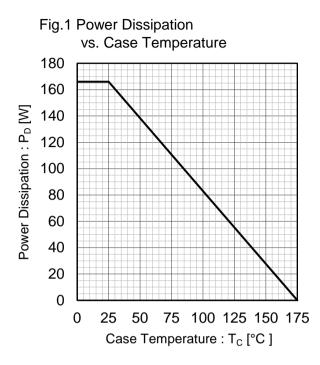


Fig.2 Collector Current vs. Case Temperature 60 50 Collector Current : Ic [A] 40 30 20 10  $T_i \leq 175^{\circ}C_i$ √<sub>GE</sub> ≥ 15√ 0 25 50 75 100 125 150 175 Case Temperature : T<sub>C</sub> [°C]

1000

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Fig.3 Forward Bias Safe Operating Area

120
100
100 [V]100
40
20  $T_{j} \le 175^{\circ}C$ ,  $V_{GE} = 15V$ 0
200
400
600
800
Collector To Emitter Voltage:  $V_{CE}[V]$ 

Fig.4 Reverse Bias Safe Operating Area

#### **•**Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

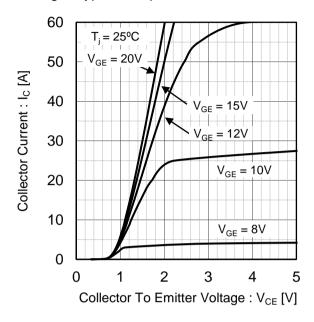


Fig.6 Typical Output Characteristics

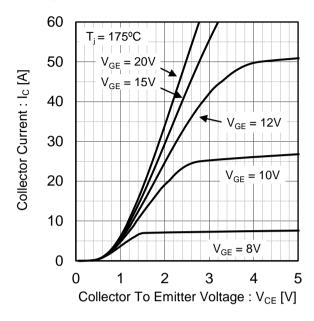


Fig.7 Typical Transfer Characteristics

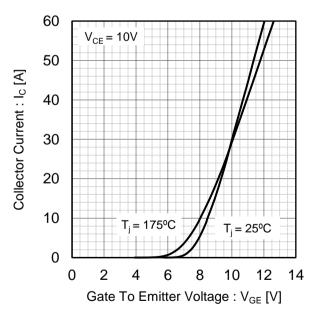
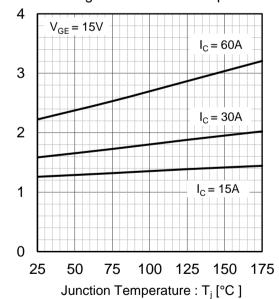


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



Collector To Emitter Saturation

Voltage: V<sub>CE(sat)</sub> [V]

Collector To Emitter Saturation

Voltage: V<sub>CE(sat)</sub> [V]

#### ● Electrical Characteristic Curves

Collector To Emitter Saturation

Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage

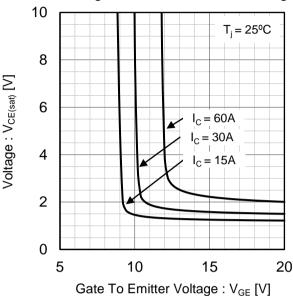


Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage

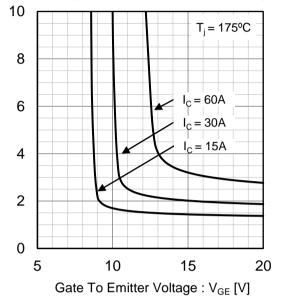


Fig.11 Typical Capacitance vs. Collector To Emitter Voltage

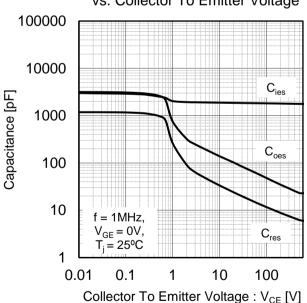
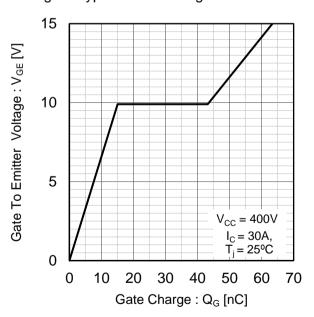


Fig.12 Typical Gate Charge



#### Electrical Characteristic Curves

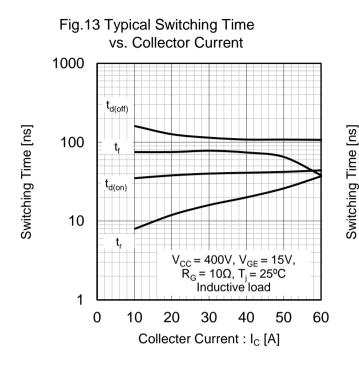


Fig.15 Typical Switching Energy Losses vs. Collector Current

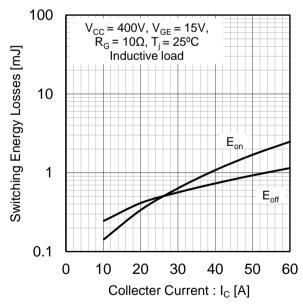
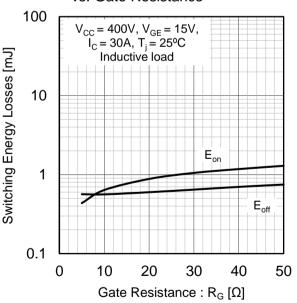


Fig.16 Typical Switching Energy Losses vs. Gate Resistance



Datasheet RGE60TS65DGC13

#### Electrical Characteristic Curves

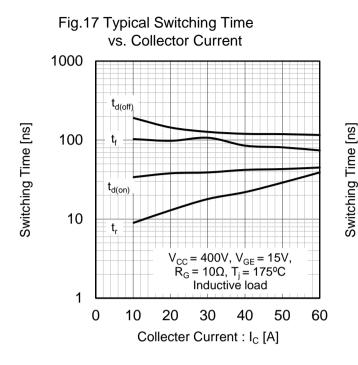


Fig.18 Typical Switching Time vs. Gate Resistance 1000  $t_{d(off)}$ 100 10  $V_{CC}$  = 400V,  $V_{GE}$  = 15V,  $I_{C}$  = 30A,  $T_{j}$  = 175°C Inductive load 1 0 10 20 30 50 Gate Resistance :  $R_G[\Omega]$ 

Fig.19 Typical Switching Energy Losses vs. Collector Current 100  $V_{CC} = 400V, V_{GE} = 15V,$   $R_G = 10\Omega, T_j = 175^{\circ}C$ 

Switching Energy Losses [mJ] Inductive load 10  $\mathsf{E}_{\mathsf{on}}$ 1  $\mathsf{E}_{\mathsf{off}}$ 0.1 0 10 20 30 40 50 60 Collecter Current : I<sub>C</sub> [A]

vs. Gate Resistance 100  $V_{CC}$  = 400V,  $V_{GE}$  = 15V,  $I_{C}$  = 30A,  $T_{j}$  = 175°C Inductive load Switching Energy Losses [mJ] 10  $\mathsf{E}_{\mathsf{on}}$ 1  $\mathsf{E}_{\mathsf{off}}$ 0.1 0 10 20 30 50 Gate Resistance :  $R_G[\Omega]$ 

Fig.20 Typical Switching Energy Losses

#### Electrical Characteristic Curves

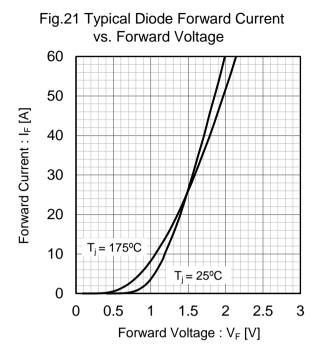
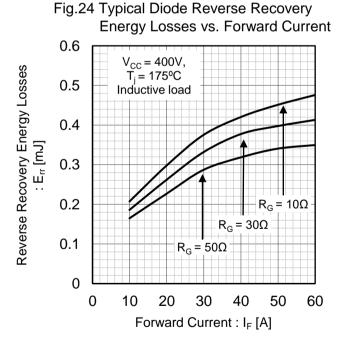


Fig.22 Typical Diode Reverce Recovery Time vs. Forward Current 400 Reverse Recovery Time: t<sub>rr</sub>[ns] 300  $T_i = 175^{\circ}C$ 200 100  $T_i = 25^{\circ}C$  $V_{CC} = 400V,$   $di_F/dt = 500A/\mu s$ Inductive load 0 0 10 20 30 40 50 60 Forward Current : I<sub>F</sub> [A]

Fig.23 Typical Diode Reverse Recovery Current vs. Forward Current 30 Reverse Recovery Current: Irr[A] 25 20  $T_i = 175^{\circ}C$ 15 10  $T_{i} = 25^{\circ}C$  $V_{CC} = 400V$ , di<sub>F</sub>/dt = 500A/µs 5 Inductive load 0 0 10 20 30 40 50 60 Forward Current : I<sub>F</sub> [A]



#### **•**Electrical Characteristic Curves

Fig.25 Typical IGBT Transient Thermal Impedance

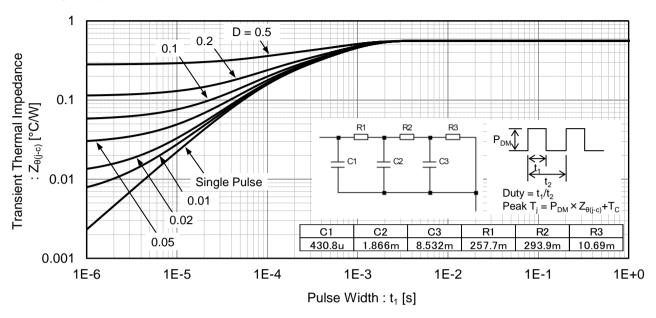
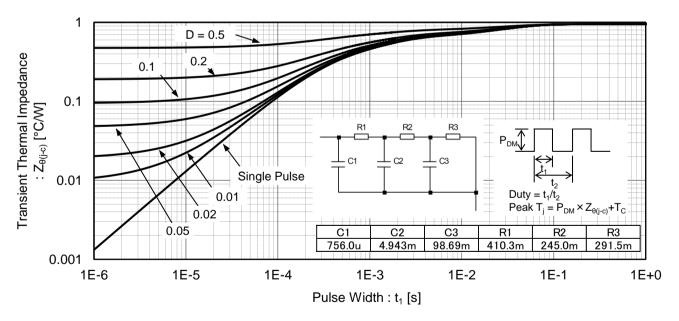


Fig.26 Typical Diode Transient Thermal Impedance



## ●Inductive Load Switching Circuit and Waveform and Short Circuit

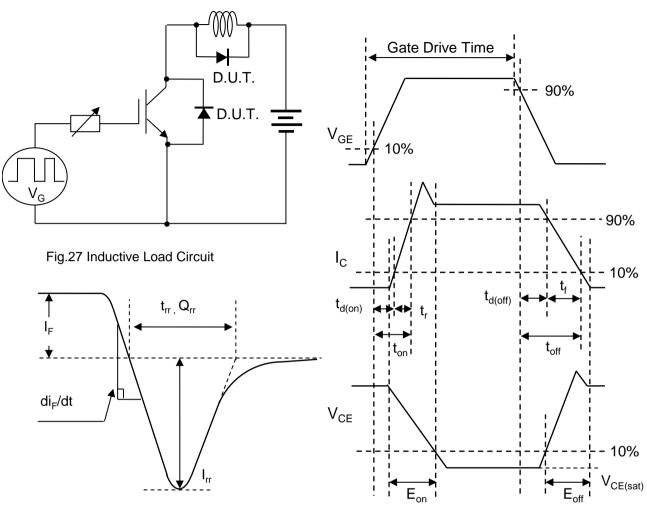


Fig.28 Diode Reverse Recovery Waveform

Fig.29 Inductive Load Waveform

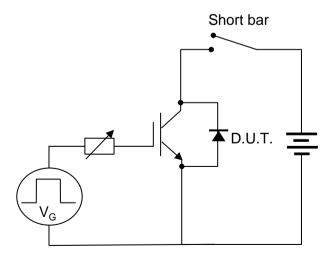


Fig.30 Short Circuit

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